

**Poster Session**

P1	One-Dimensional Wolter Mirror for Achromatic Hard X-ray microscopy	S. Matsuyama, N. Kidani, T. Wakioka, H. Mimura and K. Yamauchi	<i>Osaka University</i>
P2	Development of Advanced Kirkpatrick-Baez Mirror for Achromatic hard X-ray Microscopy	N. Kidani, S. Matsuyama, T. Wakioka, S. Kitamura, H. Mimura and K. Yamauchi	<i>Osaka University</i>
P3	Fabrication of Ultraprecision Millimeter-thick Neutron Focusing Supermirror by Numerically Controlled Local Wet Etching and Low-pressure Polishing	F. Yamaga <sup>1</sup> , M. Nagano <sup>1</sup> , K. Yamasaki <sup>1</sup> , N. Zettsu <sup>1</sup> , D. Yamazaki <sup>2</sup> , R. Maruyama <sup>2</sup> , K. Soyama <sup>2</sup> and K. Yamamura <sup>1</sup>	<sup>1</sup> <i>Osaka University</i> <sup>2</sup> <i>JAEA</i>
P4	Advancement on Reproduction of <i>Morpho-Butterfly</i> 's color - Fabrication and Simulation Analysis-	A. Saito <sup>1,2,3</sup> , J. Murase <sup>1</sup> , M. Yonezawa <sup>1</sup> , M. Akai-Kasaya <sup>1</sup> , and Y. Kuwahara <sup>1</sup>	<sup>1</sup> <i>Osaka University</i> <sup>2</sup> <i>SPring-8/RIKEN</i> <sup>3</sup> <i>JST/PRESTO</i>
P5	Excitation, Propagation, and Focusing of Surface Plasmon Polaritons via A Pair of Subwavelength Holes through Silver Thin Film	Y. Oshikane, M. Nakano, and H. Inoue	<i>Osaka University</i>
P6	Development of Side-By-Side Kirkpatrick-Baez Mirror for High-Density X-ray Nanobeam	T. Wakioka, S. Matsuyama, N. Kidani, H. Mimura, Y. Sano, and K. Yamauchi	<i>Osaka University</i>
P7	Figuring of Damage-Free Cylindrical Silicon Crystal Substrate for a Focusing X-ray Spectrometer by Plasma Chemical Vaporization Machining	M. Hosoda <sup>1</sup> , M. Nagano <sup>1</sup> , N. Zettsu <sup>1</sup> , S. Shimada <sup>2</sup> , K. Taniguchi <sup>3</sup> and K. Yamamura <sup>1</sup>	<sup>1</sup> <i>Osaka University</i> <sup>2</sup> <i>Osaka Electro -Communication University</i> <sup>3</sup> <i>Techno-X Co., Ltd.</i>
P8	Ray-tracing Analysis of a Graded Multilayer Mirror	H. Yokoyama, N. Mimura, T. Kimura, S. Imai, S. Matsuyama, Y. Sano and K. Yamauchi	<i>Osaka University</i>
P9	Nano-scale Elemental Analysis using SR-STM -Evaluation of Elemental Contrast for Adsorbed Nano-Structures on the Semiconductor Surface-	H. Notsu <sup>1,2</sup> , A. Saito <sup>1,2,3</sup> , G. Ohzeki <sup>1,2</sup> , T. Tanaka <sup>1,2</sup> , Y. Takagi <sup>2,4</sup> , Y. Tanaka <sup>2</sup> , H. Matsuno <sup>1,2</sup> , Y. Kohmura <sup>2</sup> , M. Akai-Kasaya <sup>1</sup> , T. Ishikawa <sup>2</sup> , Y. Kuwahara <sup>1,2</sup> and M. Aono <sup>5</sup>	<sup>1</sup> <i>Osaka University</i> <sup>2</sup> <i>SPring-8/RIKEN</i> <sup>3</sup> <i>JST/PRESTO</i> <sup>4</sup> <i>Inst. for Molecular Science</i> <sup>5</sup> <i>NIMS</i>
P10	Phase-Shifting Point Diffraction Interferometer with Spherical Reference Wavefronts Generated by Two Optical Fibers	N. Ogawa, Y. Oshikane, H. Inoue and M. Nakano	<i>Osaka University</i>
P11	Fabrication of High-Precision Elliptical Neutron Focusing Supermirror with Large Clear Aperture	M. Nagano <sup>1</sup> , F. Yamaga <sup>1</sup> , N. Zettsu <sup>1</sup> , D. Yamazaki <sup>2</sup> , R. Maruyama <sup>2</sup> , K. Soyama <sup>2</sup> , and K. Yamamura <sup>1</sup>	<sup>1</sup> <i>Osaka University</i> <sup>2</sup> <i>JAEA</i>
P12	Fabrication of Metallodielectric Plasmonic Nanoshell Arrays for A Label-Free Immunoassay Based on NIR-light Responsive LSPR	S. Uchida, K. Yamamura and N. Zettsu	<i>Osaka University</i>
P13	Development of High-resolution X-ray Diffraction Microscopy using Kirkpatrick and Baez Mirrors	R. Tsutsumi <sup>1</sup> , Y. Takahashi <sup>1</sup> , N. Zettsu <sup>1</sup> , A. Suzuki <sup>1</sup> , Y. Nishino <sup>2</sup> , E. Matsubara <sup>3</sup> , T. Ishikawa <sup>4</sup> and K. Yamauchi <sup>1</sup>	<sup>1</sup> <i>Osaka University</i> <sup>2</sup> <i>Hokkaido University</i> <sup>3</sup> <i>Kyoto University</i> <sup>4</sup> <i>SPring-8/RIKEN</i>
P14	Development of Wavefront Measurement Method for Hard X-ray Adaptive Optics System	T. Kimura <sup>1</sup> , S. Handa <sup>1</sup> , H. Mimura <sup>1</sup> , H. Yumoto <sup>2</sup> , H. Yokoyama <sup>1</sup> , Y. Sano <sup>1</sup> , K. Tamasaku <sup>1,3</sup> , Y. Nishino <sup>3</sup> , M. Yabashi <sup>2</sup> , T. Ishikawa <sup>2,3</sup> and K. Yamauchi <sup>1</sup>	<sup>1</sup> <i>Osaka University</i> <sup>2</sup> <i>SPring-8/JASRI</i> <sup>3</sup> <i>SPring-8/RIKEN</i>
P15	Sensing of DNA Solution by Silicon-Oxide-Gap-Oxide-Silicon Structure	T. Kamiya, R. Yamada, J. Uchikoshi, K. Arima and M. Morita	<i>Osaka University</i>
P16	Electrical Characterization of DNA Solutions Using Metal-Gap-Insulator-Semiconductor Devices	T. Hirokane, Y. Doi, T. Furukawa, J. Uchikoshi, K. Arima, and M. Morita	<i>Osaka University</i>
P17	First-principle Analysis Silicon Etching by Hydrogen Radical -Diffusion of Absorbed Hydrogen Atom on Si(001) 2x1 Surface-	K. Inagaki, K. Hirose, Y. Morikawa and K. Yasutake	<i>Osaka University</i>
P18	Electroluminescence in Metal-Oxide-Semiconductor Tunnel Diodes on Ultrathin Silicon-on-Insulator Substrates	K. Matsumura, A. Tsuchida, R. Yamada, Y. Oshikane, J. Uchikoshi, K. Arima and M. Morita	<i>Osaka University</i>

P19	Investigation of Structural Change in TiN/HfLaSiO Gate Stack Induced by High-temperature Annealing	T. Yamamoto <sup>1,2</sup> , S. Ogawa <sup>1</sup> , H. Arimura <sup>2</sup> , M. Saeki <sup>2</sup> , N. Kitano <sup>2</sup> , T. Hosoi <sup>2</sup> , T. Shimura <sup>2</sup> and H. Watanabe <sup>2</sup>	<sup>1</sup> Toray Research Center <sup>2</sup> Osaka University
P20	Investigation of High-k Bulk and Interface Defects in Poly-Si/TiN/HfLaSiO/SiO <sub>2</sub> Stacks using Charge Pumping Technique	M. Saeki, H. Arimura, N. Kitano T. Hosoi, T. Shimura and H. Watanabe	Osaka University
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P22	Improvement of Thickness Uniformity of Si Layer in SOI Wafer by Numerically Controlled Sacrificial Oxidation Using Atmospheric-Pressure Plasma with Electrode Array System	K. Yoshinaga, Y. Sano, H. Mimura, S. Matsuyama, and K. Yamauchi	Osaka University
P23	Interaction Between Dangling Bonds and Passivants at Ge/GeO <sub>2</sub> Interfaces: A Theoretical Study	S. Saito and T. Ono	Osaka University
P24	Dependence of Miscut Angles on Straightness of Step Edges of Si(111) Surfaces Flattened by Ultra-low Dissolved Oxygen Water	H. Sakane, T. Teramura, J. Uchikoshi, M. Morita and K. Arima	Osaka University
P25	Open Air Deposition of Silicon Oxide Films at Room Temperature Using Atmospheric-Pressure Plasma Jet	K. Higashida <sup>1</sup> , K. Nakamura <sup>1</sup> , T. Shibata <sup>2</sup> , T. Yamada <sup>1</sup> , H. Ohmi <sup>1</sup> , H. Kakiuchi and K. Yasutake <sup>1</sup>	<sup>1</sup> Osaka University <sup>2</sup> Panasonic Electric Works Co., Ltd.
P26	Consideration of Photo-etching Mechanism of Si with N-fluoropyridinium Salt	K. Tsukamoto <sup>1</sup> , J. Uchikoshi <sup>1</sup> , M. Otani <sup>1</sup> , S. Goto <sup>1</sup> , Y. Ie <sup>1</sup> , T. Nagai <sup>2</sup> , K. Adachi <sup>2</sup> , K. Arima <sup>1</sup> and M. Morita <sup>1</sup>	<sup>1</sup> Osaka University <sup>2</sup> Daikin Industries, Ltd.
P27	Residual Order and Rate Enhancement of SiGe Thermal Oxidation	T. Shimura, Y. Okamoto, D. Shimokawa, T. Inoue, T. Hosoi and H. Watanabe	Osaka University
P28	Impact of La and Al Composition Ratio on the Electrical Properties of La-Al-O Higher- <i>k</i> Gate Dielectrics	H. Arimura <sup>1</sup> , T. Ando <sup>1,2</sup> S. L. Brown <sup>2</sup> , A. Kellock <sup>3</sup> , A. Callegari <sup>2</sup> , M. Copel <sup>2</sup> , R. Haight <sup>2</sup> , H. Watanabe <sup>1</sup> and V. Narayanan <sup>2</sup>	<sup>1</sup> Osaka University <sup>2</sup> IBM T. J. Watson <sup>3</sup> IBM Almaden
P29	Thermal Robustness and Improved Electrical Properties of Ultrathin Germanium Oxynitride Gate Dielectric	K. Kutsuki, I. Hideshima T. Hosoi, T. Shimura and H. Watanabe	Osaka University
P30	Selective Transportation of Gold Nanoparticles Encapsulated with TFG Subunit Dimers and Their Plasmonic Characteristics	T. Hashimoto <sup>1</sup> , B. Zheng <sup>2,3</sup> , M. Fukuta <sup>1,3</sup> , K. Gamo <sup>1</sup> , N. Zettsu <sup>1,3</sup> , I. Yamashita <sup>2,3</sup> , Y. Uraoka <sup>2,3</sup> and H. Watanabe <sup>1,3</sup>	<sup>1</sup> Osaka University <sup>2</sup> NAIST <sup>3</sup> JST/CREST
P31	Critical Titanium Coverage on SiO <sub>2</sub> for Selective Adsorption of Ti-binding Ferritin	K. Gamo <sup>1</sup> , M. Fukuta <sup>1,3</sup> , T. Hashimoto <sup>1</sup> , B. Zheng <sup>2,3</sup> , N. Zettsu <sup>1,3</sup> , I. Yamashita <sup>2,3</sup> , Y. Uraoka <sup>2,3</sup> and H. Watanabe <sup>1,3</sup>	<sup>1</sup> Osaka University <sup>2</sup> NAIST <sup>3</sup> JST/CREST
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P33	High-performance Organic Single Crystal Transistor with Sub-micrometer Channel	T. Fujiwara <sup>1</sup> , M. Akai-Kasaya <sup>1</sup> , A. Saito <sup>1,2</sup> , J. Takeya <sup>1,2</sup> and Y. Kuwahara <sup>1</sup>	<sup>1</sup> Osaka University <sup>2</sup> JST/PREST
P34	Theoretical Investigation of Phthalocyanine Dimer	T. Yasuda, S. Yanagisawa, Y. Morikawa, K. Manseki, and S. Yanagida	Osaka University
P35	Excellent Electrical Property of Ge-MIS Devices with ZrO <sub>2</sub> High- <i>k</i> Gate Dielectrics	T. Hosoi <sup>1</sup> , G. Okamoto <sup>1</sup> , K. Kutsuki <sup>1</sup> , J. Harries <sup>2</sup> , A. Yoshigoe <sup>2</sup> , Y. Teraoka <sup>2</sup> , T. Shimura <sup>1</sup> and H. Watanabe <sup>1</sup>	<sup>1</sup> Osaka University <sup>2</sup> JAEA
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P37	Tunneling-current-induced Light Emission From PTCDI-C7 Thin Films on Graphite and Au(111) at the Solid-liquid Interface	Y. Miyake <sup>1</sup> , A. Fujiki <sup>1</sup> , M. Kasaya-Akai <sup>1</sup> , A. Saito <sup>1,2</sup> , and Y. Kuwahara <sup>1</sup>	<sup>1</sup> Osaka University <sup>2</sup> JST/PREST

P38	Tunneling-current-induced Light Emission from Chiral Binaphthylene-perylenebiscarboxydiimide Dimer	A. Fujiki <sup>1</sup> , Y. Miyake <sup>1</sup> , M. Kasaya-Akai <sup>1</sup> , A. Saito <sup>1,2</sup> , and Y. Kuwahara <sup>1</sup>	<sup>1</sup> <i>Osaka University</i> <sup>2</sup> <i>JST/PREST</i>
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P40	Investigation of Carrier Transport Property in a High-oriented Regioregular Poly(3-hexylthiophene) Monolayer	Y. Okuaki <sup>1</sup> , M. Kasaya-Akai <sup>1</sup> , A. Saito <sup>1</sup> , S. Nagano <sup>2</sup> , and Y. Kuwahara <sup>1</sup>	<sup>1</sup> <i>Osaka University</i> <sup>2</sup> <i>Nagoya University</i>
P41	Tunneling-current-induced Light Emission from Isolated Single-walled Carbon Nanotubes	Y. Miki <sup>1</sup> , N. Ozawa <sup>1</sup> , A. Fujiki <sup>1</sup> , K. Okamura <sup>1</sup> , M. Kasaya-Akai <sup>1</sup> , A. Saito <sup>1,2</sup> , H. Tabata <sup>1</sup> , S. Honda <sup>3</sup> , M. Katayama <sup>1</sup> and Y. Kuwahara <sup>1</sup>	<sup>1</sup> <i>Osaka University</i> <sup>2</sup> <i>JST/PREST</i> <sup>3</sup> <i>University of Hyogo</i>
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P51	First-Principles Study of CO Oxidation on Carbon Alloy Catalysts	S. Iseki, K. Inagaki and Y. Morikawa	<i>Osaka University</i>
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P53	Autothermal Reforming of Methane Over La-Ce-Co Promoted Ni/γ-Al <sub>2</sub> O <sub>3</sub> Catalysts	M. A. Khan <sup>1</sup> , S.I. Woo <sup>2</sup> , S. Ikeda <sup>1</sup> and M. Matsumura <sup>1</sup>	<sup>1</sup> <i>Osaka University</i> <sup>2</sup> <i>Korea Advanced Institute of Science and Technology</i>
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P57	Atmospheric Pressure Plasma Liquid Deposition of Copper Nanoparticles onto Poly(4-vinylpyrdine)-grafted-poly(tetrafluoroethylene) Surface	H. Akiyama, Y. Oshikane, N. Zettsu and K. Yamamura	<i>Osaka University</i>
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P60	Simultaneous Measurement of Tunneling Current and Force of The Cu (110)-O Surface Using Low Temperature Noncontact AFM	Z. Ma, Y. Naitoh, Y. J. Li and Y. Sugawara	<i>Osaka University</i>
P61	Spin-Orbit Coupling and Noncollinear Magnetism in PAW Density-Functional Calculations	M. Heide and T. Ono	<i>Osaka University</i>

P62	Impact of Nitrogen Incorporation into Al <sub>2</sub> O <sub>3</sub> Gate Dielectrics on Flatband Voltage Stability in 4H-SiC MIS Devices	T. Hosoi <sup>1</sup> , Y. Kagei <sup>1</sup> , T. Kirino <sup>1</sup> , S. Mitani <sup>2</sup> , Y. Nakano <sup>2</sup> , T. Nakamura <sup>2</sup> , T. Shimura <sup>1</sup> and H. Watanabe <sup>1</sup>	<sup>1</sup> <i>Osaka University</i> <sup>2</sup> <i>ROHM Co., Ltd.</i>
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P72	Study on Molybdenum Oxide Encapsulated inside Carbon Nanotubes Using Transmission Electron Microscope	R. Sagawa <sup>1</sup> , W. Togashi <sup>1</sup> , T. Akita <sup>2</sup> and Y. Takai <sup>1</sup>	<sup>1</sup> <i>Osaka University</i> <sup>2</sup> <i>AIST</i>
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P76	Influence of Process Parameters on the Material Properties of Microcrystalline Si Prepared Using Atmospheric-Pressure Very High-Frequency Plasma	K. Tabuchi, A. Hirano, T. Yamada, H. Ohmi, H. Kakiuchi, and K. Yasutake	<i>Osaka University</i>
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P78	Role of Correlation Effects in Many-Electron System: Toward Overcoming Unreliability Problems of Density Functional Theory	M. Kojo and K. Hirose	<i>Osaka University</i>
P79	Processing Characteristics in Catalyst-Referred Etching of 4H-SiC (0001) Substrates	T. Okamoto <sup>1</sup> , Y. Sano <sup>1</sup> , K. Tachibana <sup>1</sup> , K. Arima <sup>1</sup> , A. N. Hattori <sup>1</sup> , K. Yagi <sup>2</sup> , J. Murata <sup>1</sup> , S. Sadakuni <sup>1</sup> , and K. Yamauchi <sup>1</sup>	<sup>1</sup> <i>Osaka University</i> <sup>2</sup> <i>Ebara Corp.</i>